

TECHNICAL DATA
DATA SHEET 335, REV. C

POWER SCHOTTKY RECTIFIER Very Low Voltage Drop

DESCRIPTION: 30 VOLT, 15 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC SHD-1/1B PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @ $T_C = 25\text{ }^\circ\text{C}$ UNLESS OTHERWISE SPECIFIED.

| RATING | SYMBOL | MAX. | UNITS |
|--|-----------------|-----------------|--------------------|
| PEAK INVERSE VOLTAGE | PIV | 30 | Volts |
| MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ $T_C=100\text{ }^\circ\text{C}$) | I_O | 15 | Amps |
| MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT ($t=8.3\text{ms}$, Sine) | I_{FSM} | 280 | Amps |
| MAXIMUM JUNCTION CAPACITANCE ($V_r=5\text{V}$) | C_T | 1100 | pF |
| MAXIMUM THERMAL RESISTANCE (Junction to Mounting Surface, Cathode) | $R_{\theta JC}$ | 1.70 | $^\circ\text{C/W}$ |
| MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE | Top/Tstg | -65 to + 150 | $^\circ\text{C}$ |

ELECTRICAL CHARACTERISTICS

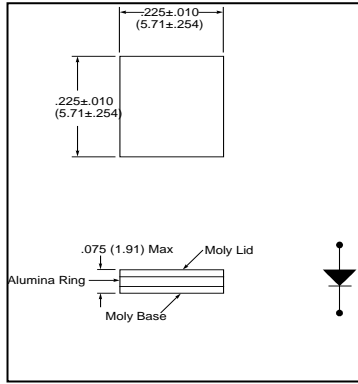
| CHARACTERISTIC | SYMBOL | MAX. | UNITS |
|--|--------|--------------|-------|
| MAXIMUM FORWARD VOLTAGE DROP, Pulsed ($I_f = 15\text{ Amps}$) $T_J = 25\text{ }^\circ\text{C}$ $T_J = 125\text{ }^\circ\text{C}$ | V_f | 0.49 0.39 | Volts |
| MAXIMUM REVERSE CURRENT (I_r @ 30V PIV) $T_J = 25\text{ }^\circ\text{C}$ $T_J = 125\text{ }^\circ\text{C}$ | I_r | 2.0 100 | mA |

SENSITRON

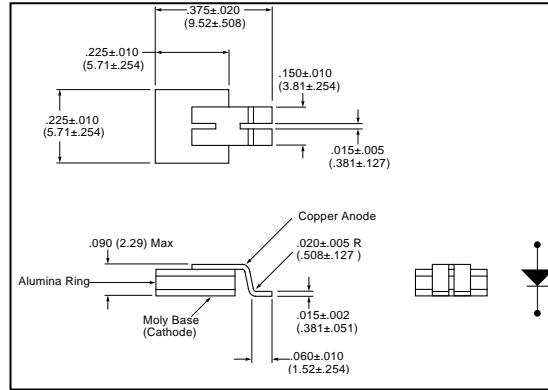
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MECHANICAL DIMENSIONS: In Inches / mm

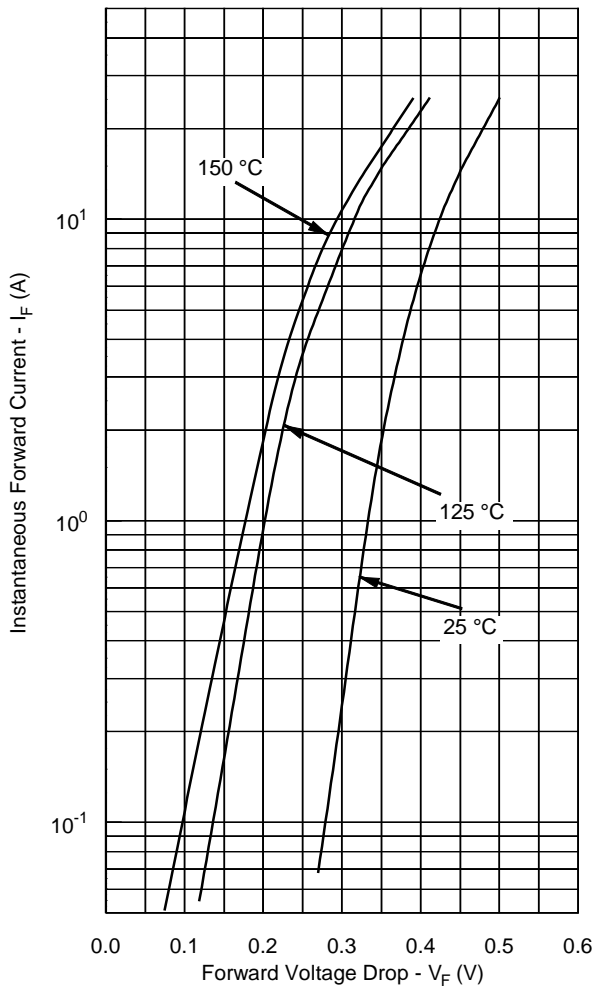
SHD-1



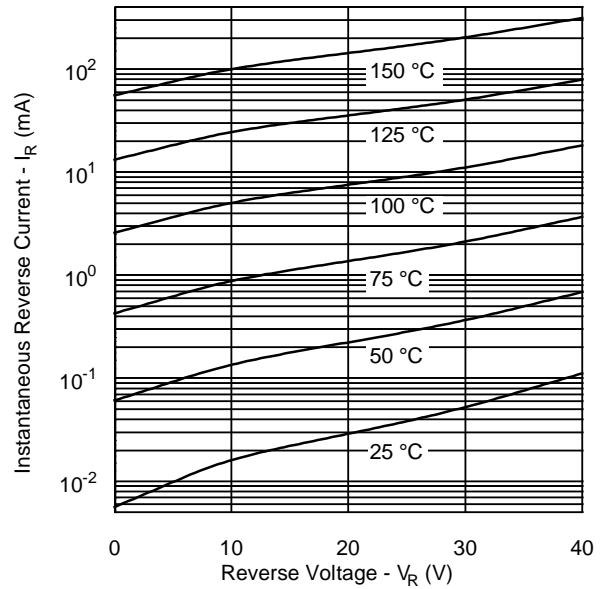
SHD-1B



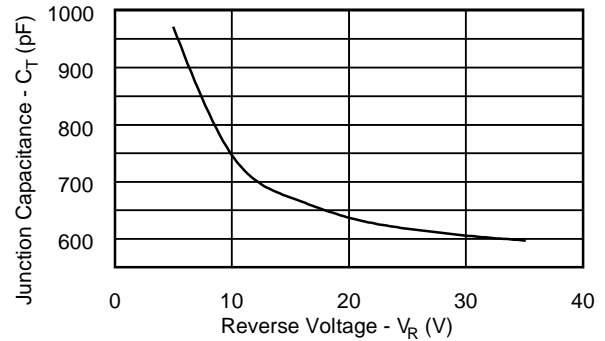
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



SENSITRON

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